Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOS VII)

TK12A55D

Switching Regulator Applications

• Low drain-source ON-resistance: RDS (ON) = $0.48 \Omega(\text{typ.})$

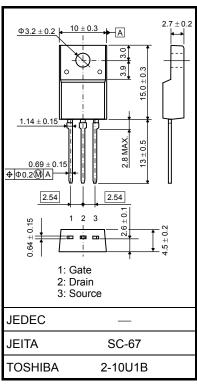
• High forward transfer admittance: $|Y_{fs}| = 6.0 \text{ S (typ.)}$

• Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 550 \text{ V)}$

• Enhancement mode: $V_{th} = 2.0 \text{ to } 4.0 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA)}$

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit | |
|---------------------------|-----------------------|------------------|------------|------|--|
| Drain-source voltage | | V_{DSS} | 550 | V | |
| Gate-source voltage | | V_{GSS} | ±30 | V | |
| Drain current | DC (Note 1) | I _D | 12 | Α | |
| | Pulse (Note 1) | I _{DP} | 48 | A | |
| Drain power dissipati | on (Tc = 25°C) | P _D | 45 | W | |
| Single pulse avalance | ne energy (Note 2) | E _{AS} | 317 | mJ | |
| Avalanche current | | I _{AR} | 12 | Α | |
| Repetitive avalanche | energy (Note 3) | E _{AR} | 4.5 | mJ | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature range | | T _{stg} | -55 to 150 | °C | |



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

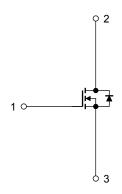
| Characteristics | Symbol | Max | Unit |
|--|------------------------|------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 2.78 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 62.5 | °C/W |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 90 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}(\text{initial})$, L = 3.8 mH, $R_G = 25 \Omega$, $I_{AR} = 12 \text{ A}$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.



Start of commercial production 2009-02



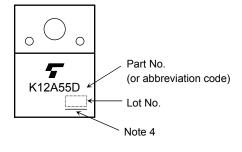
Electrical Characteristics (Ta = 25°C)

| Chara | acteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|------------------------------|----------------|----------------------|--|-----|------|------|------|
| Gate leakage cur | rent | I _{GSS} | $V_{GS}=\pm30~V,~V_{DS}=0~V$ | _ | _ | ±1 | μА |
| Drain cut-off curre | ent | I _{DSS} | V _{DS} = 550 V, V _{GS} = 0 V | _ | _ | 10 | μА |
| Drain-source brea | akdown voltage | V (BR) DSS | I _D = 10 mA, V _{GS} = 0 V | 550 | _ | _ | V |
| Gate threshold vo | oltage | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 2.0 | _ | 4.0 | V |
| Drain-source ON | resistance | R _{DS} (ON) | V _{GS} = 10 V, I _D = 6 A | _ | 0.48 | 0.57 | Ω |
| Forward transfer | admittance | Y _{fs} | V _{DS} = 10 V, I _D = 6 A | 1.5 | 6.0 | _ | S |
| Input capacitance |) | C _{iss} | | _ | 1550 | _ | |
| Reverse transfer capacitance | | C _{rss} | V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz | _ | 7 | _ | pF |
| Output capacitance | | Coss | | _ | 165 | _ | |
| Switching time | Rise time | t _r | 10 V ID = 6 A VOUT VGS | _ | 25 | _ | |
| | Turn-on time | t _{on} | $\begin{array}{c c} \hline 0 & V & \downarrow & \downarrow \\ \hline 50 & \Omega & \downarrow & \downarrow \\ \end{array} \qquad \begin{array}{c} R_L = 33 & \Omega \end{array}$ | _ | 60 | _ | |
| | Fall time | t _f | V _{DD} ≈ 200 V | _ | 15 | _ | ns |
| | Turn-off time | t _{off} | V _{DD} ≈ 200 V Duty ≤ 1%, t _W = 10 μs | _ | 110 | _ | |
| Total gate charge | | Qg | | _ | 28 | _ | |
| Gate-source charge | | Q _{gs} | $V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 12 \text{ A}$ | _ | 18 | _ | nC |
| Gate-drain charge | | Q _{gd} | | _ | 10 | | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

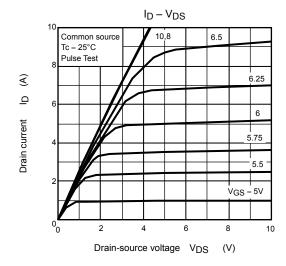
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|--|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | _ | _ | _ | 12 | Α |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 48 | Α |
| Forward voltage (diode) | V _{DSF} | I _{DR} = 12 A, V _{GS} = 0 V | _ | _ | -1.7 | V |
| Reverse recovery time | t _{rr} | I _{DR} = 12 A, V _{GS} = 0 V, | _ | 1300 | _ | ns |
| Reverse recovery charge | Q _{rr} | dl _{DR} /dt = 100 A/μs | _ | 13 | _ | μС |

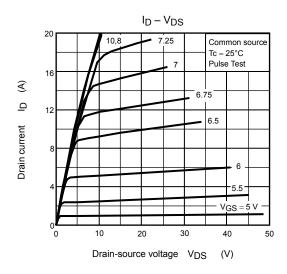
Marking

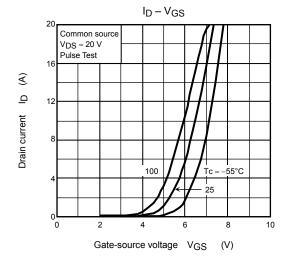


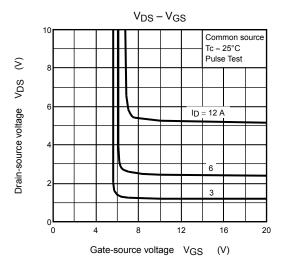
Note 4: A line under a Lot No. identifies the indication of product Labels $\hbox{[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]}$

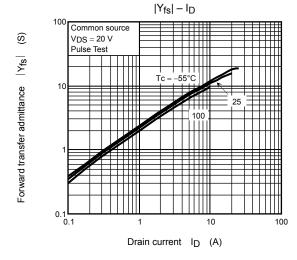
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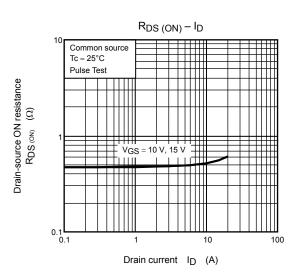


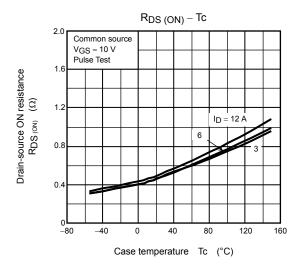


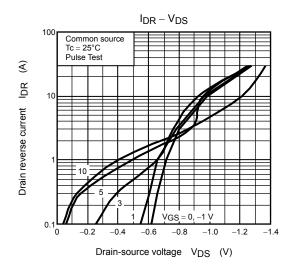


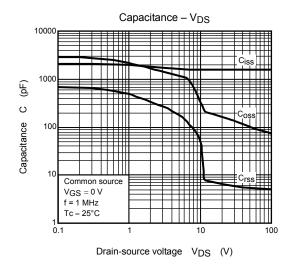


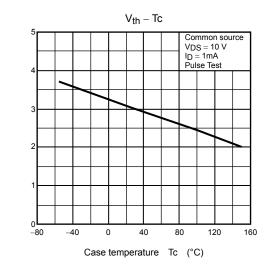


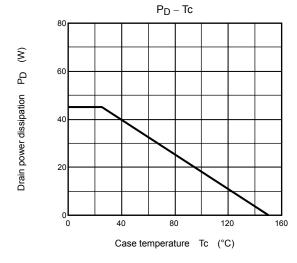


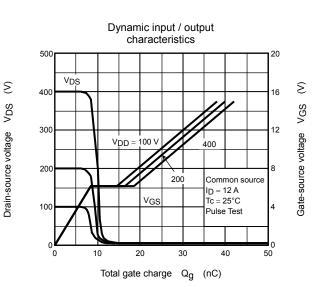








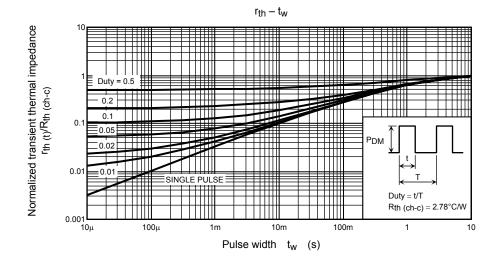


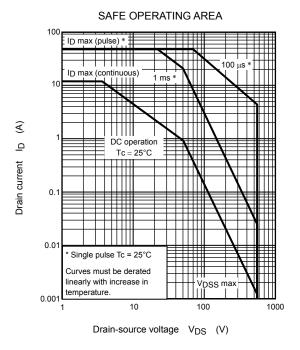


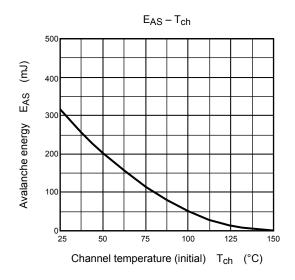
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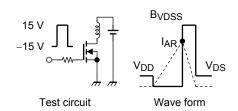
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Gate threshold voltage









$$R_G = 25~\Omega$$

$$V_{DD} = 90~V,~L = 3.8~mH$$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

5 2013-11-01

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